Product data sheet

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NXP Semiconductors



Silicon PIN diode BAP1321-02

FEATURES

- High voltage, current controlled
- RF resistor for RF attenuators and switches
- Low diode capacitance
- Low diode forward resistance
- · Very low series inductance
- For applications up to 3 GHz.

APPLICATIONS

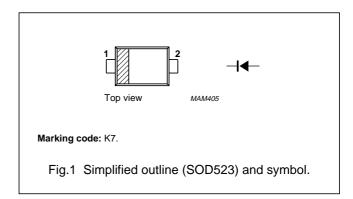
• RF attenuators and switches.

DESCRIPTION

Planar PIN diode in a SOD523 ultra small SMD plastic package.

PINNING

PIN	DESCRIPTION	
1	cathode	
2	anode	



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _R	continuous reverse voltage		_	60	V
I _F	continuous forward current		_	100	mA
P _{tot}	total power dissipation	T _s ≤ 90 °C	_	715	mW
T _{stg}	storage temperature		-65	+150	°C
T _j	junction temperature		-65	+150	°C

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ELECTRICAL CHARACTERISTICS

 $T_j = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS		MAX.	UNIT
V _F	forward voltage	I _F = 50 mA	0.95	1.1	V
I _R	reverse leakage current	V _R = 60 V	_	100	nA
C _d	diode capacitance	V _R = 0; f = 1 MHz	0.4	_	pF
		V _R = 1 V; f = 1 MHz	0.35	0.45	pF
		V _R = 20 V; f = 1 MHz	0.25	0.32	pF
r _D	diode forward resistance	f = 100 MHz; note 1			
		$I_F = 0.5 \text{ mA}$	3.4	5.0	Ω
		I _F = 1 mA	2.4	3.6	Ω
		I _F = 10 mA	1.2	1.8	Ω
		I _F = 100 mA	0.85	1.3	Ω
S ₂₁ ²	isolation	V _R = 0; f = 900 MHz	16.3	_	dB
		V _R = 0; f = 1800 MHz	11.4	_	dB
		V _R = 0; f = 2450 MHz	9.2	_	dB
S ₂₁ ²	insertion loss	I _F = 0.5 mA; f = 900 MHz	0.23	_	dB
		I _F = 0.5 mA; f = 1800 MHz	0.27	_	dB
		I _F = 0.5 mA; f = 2450 MHz	0.33	_	dB
S ₂₁ ²	insertion loss	I _F = 1 mA; f = 900 MHz	0.18	_	dB
		I _F = 1 mA; f = 1800 MHz	0.22	_	dB
		I _F = 1 mA; f = 2450 MHz	0.27	_	dB
S ₂₁ ²	insertion loss	I _F = 10 mA; f = 900 MHz	0.10	_	dB
		I _F = 10 mA; f = 1800 MHz	0.16	_	dB
		I _F = 10 mA; f = 2450 MHz	0.20	_	dB
S ₂₁ ²	insertion loss	I _F = 100 mA; f = 900 MHz	0.08	_	dB
		I _F = 100 mA; f = 1800 MHz	0.13	_	dB
		I _F = 100 mA; f = 2450 MHz	0.18	_	dB
τ∟	charge carrier life time	when switched from I_F = 10 mA to I_R = 6 mA; R_L = 100 Ω ; measured at I_R = 3 mA	0.5	-	μs
L _S	series inductance	I _F = 100 mA; f = 100 MHz	0.6	_	nH

Note

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R _{th j-s}	thermal resistance from junction to soldering point		K/W

^{1.} Guaranteed on AQL basis: inspection level S4, AQL 1.0.

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GRAPHICAL DATA

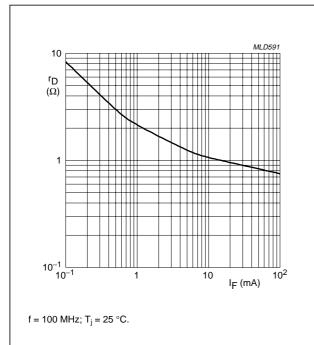
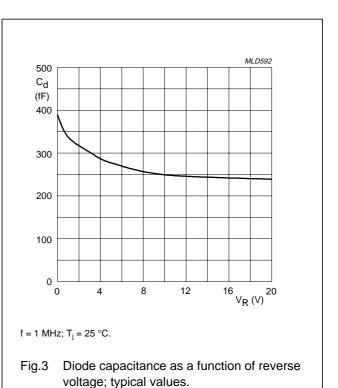
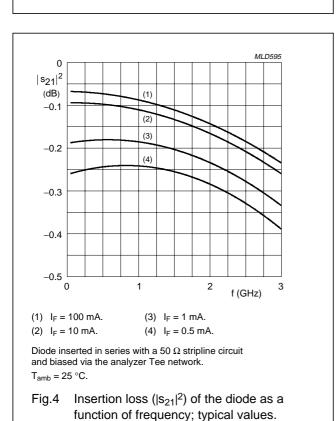
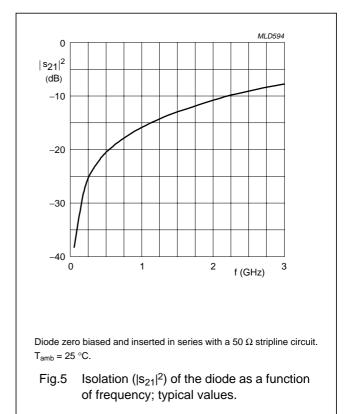


Fig.2 Forward resistance as a function of forward current; typical values.







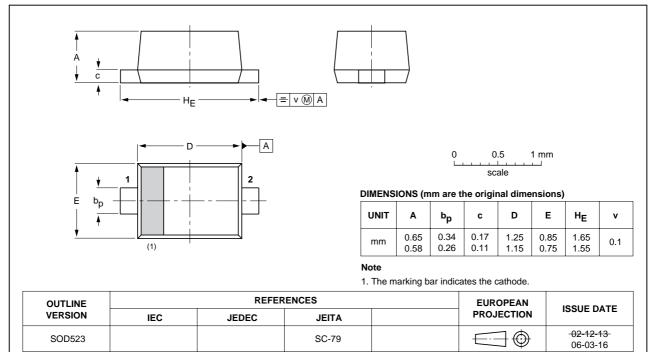
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PACKAGE OUTLINE



SOD523



Silicon PIN diode

Legal information

Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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Silicon PIN diode

Revision history

Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BAP1321-02_N_2	20080103	Product data sheet	-	BAP1321-02_1	
Modifications: • Package outline drawing on page 5 changed					
BAP1321-02_1 (9397 750 08131)	20010417	Product specification	-	-	

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